



### **60V P-Channel Enhancement Mode MOSFET**

Voltage

-60 V

Current

-3.2 A

#### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-10V,I<sub>D</sub>@-3.2A<115mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ , $I_D@-1.6A<160m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

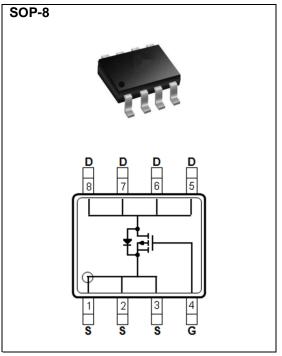
### **Mechanical Data**

• Case: SOP-8 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0029 ounces, 0.083 grams

Marking: L9433



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	-60	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-3.2		
	T <sub>A</sub> =70°C		-2.5	A	
Pulsed Drain Current <sup>(Note 1)</sup>		I <sub>DM</sub>	-12.8	Α	
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2.5		
	T <sub>A</sub> =70°C		1.6	W	
Single Pulse Avalanche Energy (Note 5)		E <sub>AS</sub>	8.2	mJ	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal resistance					
- Junction to Ambient, t≦10s (Note 6)		$R_{\theta JA}$	50	°C/W	

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-2.0	-2.42	-3.5	V		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-3.2A	-	88	115	mΩ		
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-1.6A	-	120	160			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-55V, $V_{GS}$ =0V	-	-0.01	-1.0	uA		
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	$Q_g$	$V_{DS}$ =-30V, $I_{D}$ =-3.2A, $V_{GS}$ =-10V (Note 1,2)	-	13.4	-	nC		
Gate-Source Charge	$Q_gs$		-	3.4	-			
Gate-Drain Charge	$Q_gd$		-	3.0	-			
Input Capacitance	Ciss	\/ - 20\/ \/ -0\/	-	685	-	pF		
Output Capacitance	Coss	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1.0MHZ	-	63	-			
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	29	-			
Turn-On Delay Time	td <sub>(on)</sub>	V 20V DI 400	-	7	-			
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-30V,RL=10 $\Omega$ $V_{GS}$ =-10V, R <sub>G</sub> =6.2 $\Omega$ (Note 1,2)	-	40	-	ns		
Turn-Off Delay Time	td <sub>(off)</sub>		-	23	-			
Turn-Off Fall Time	t <sub>f</sub>		-	10	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	ı				-3.2	Α		
Diode Forward Current	I <sub>S</sub>		_	-	-5.2	^		
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.78	-1.0	V		

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH,  $I_{AS}$ =12.8A,  $V_{DD}$ =25V,  $V_{GS}$ =10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

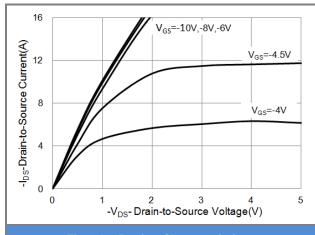
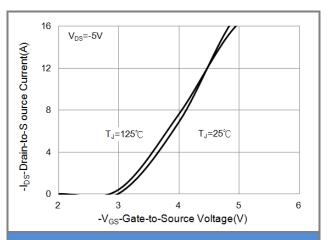


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

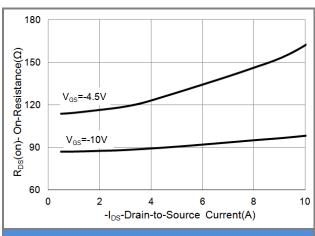


Fig.3 On-Resistance vs. Drain Current

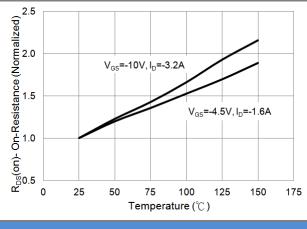
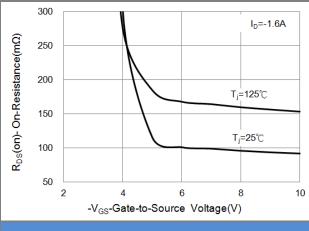
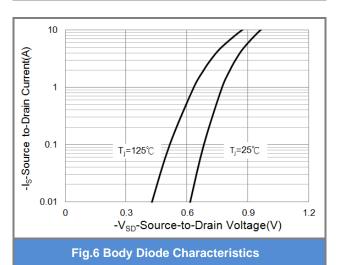


Fig.4 On-Resistance vs. Junction temperature







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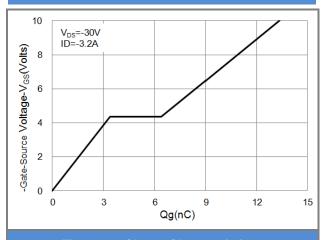


Fig.7 Gate-Charge Characteristics

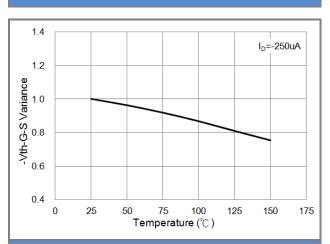
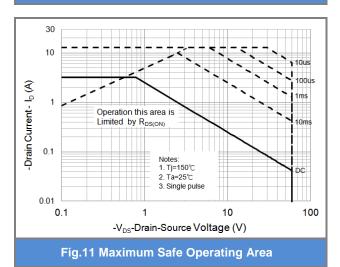


Fig.9 Threshold Voltage Variation with Temperature.



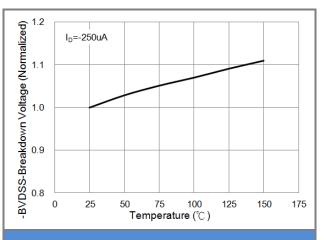


Fig.8 Breakdown Voltage Variation vs. Temperature

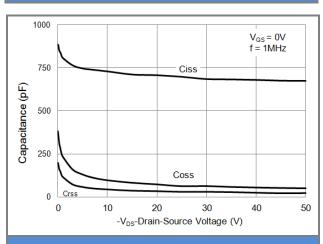
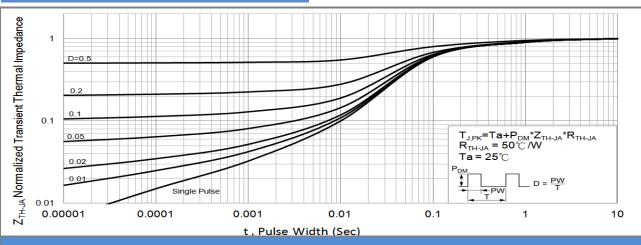


Fig.10 Capacitance vs. Drain-Source Voltage.





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**Fig.12 Normalized Thermal Transient Impedance** 

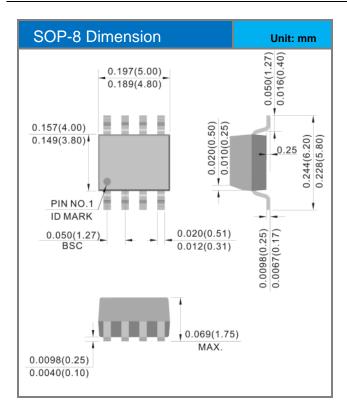


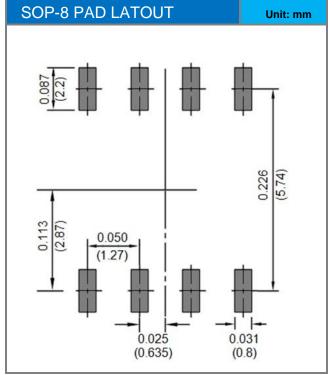


#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJL9433_R2_00001	SOP-8	2.5K pcs / 13" reel	L9433	Halogen free	

### Packaging Information & Mounting Pad Layout









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